

## EAST Search History

| Ref # | Hits | Search Query   | DBs   | Default Operator | Plurals | Time Stamp          |
|-------|------|--|---|------------------|---------|---------------------|
| S1    | 4    | ("20020074612"   "5439831"   "5525529"   "5719424").PN.  | US-PGPUB;<br>USPAT  | OR               | OFF     | 2009/03/29<br>14:41 |
| S2    | 1    | ("6159813").PN.  | USPAT; USOCR  | OR               | OFF     | 2009/03/29<br>14:45 |
| S3    | 1    | ("20070093030").PN.  | US-PGPUB;<br>USPAT; USOCR   | OR               | OFF     | 2009/03/29<br>14:56 |
| S4    | 88   | (boron with diffus\$4 with reduc\$4) and ((silicon adj nitride) and source and drain and ((halo or LDD) with implant\$5)                             | US-PGPUB;<br>USPAT;<br>USOCR; FPRS;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | OFF     | 2009/03/29<br>15:01 |
| S5    | 13   | (boron with diffus\$4 with reduc\$4) and ((silicon adj nitride) with stress) and source and drain and (halo or LDD)                                  | US-PGPUB;<br>USPAT;<br>USOCR; FPRS;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | OFF     | 2009/03/29<br>15:27 |
| S6    | 5    | (boron with diffus\$4 with reduc\$4) and ((silicon adj nitride) and source and drain and ((halo or LDD) with implant\$5) and (tensile with strain)   | US-PGPUB;<br>USPAT;<br>USOCR; FPRS;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | OFF     | 2009/03/30<br>11:41 |
| S7    | 0    | (boron with diffus\$4 with reduc\$4) and ((silicon adj nitride) with (tensile with strain)) and source and drain and ((halo or LDD) with implant\$5) | US-PGPUB;<br>USPAT;<br>USOCR; FPRS;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | OFF     | 2009/03/30<br>11:48 |
| S8    | 0    | (boron with diffus\$4 with reduc\$4) and ((silicon adj nitride) with (tensile with strain)) and source and drain                                     | US-PGPUB;<br>USPAT;<br>USOCR; FPRS;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | OFF     | 2009/03/30<br>11:48 |
| S9    | 102  | ((silicon adj nitride) with (tensile with strain)) and source and drain  | US-PGPUB;<br>USPAT;<br>USOCR; FPRS;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | OFF     | 2009/03/30<br>11:49 |

|     |      |  |   |    |     |                     |
|-----|------|--|---|----|-----|---------------------|
| S10 | 12   | S9 and ((halo or LDD) with implant\$5)   | US-PGPUB;<br>USPAT;<br>USOCR; FPRS;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | OFF | 2009/03/30<br>11:49 |
| S11 | 313  | (boron with diffus\$5) and ((halo or pocket) with implant\$5) and (FET or MOSFET or PFET or NFET)                        | US-PGPUB;<br>USPAT;<br>USOCR; FPRS;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | OFF | 2009/03/31<br>11:47 |
| S12 | 93   | (boron with diffus\$5) and ((halo or pocket) with implant\$5) and (FET or MOSFET or PFET or NFET) and (stress or strain) | US-PGPUB;<br>USPAT;<br>USOCR; FPRS;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | OFF | 2009/03/31<br>11:48 |
| S13 | 13   | ("5525529").URPN.  | USPAT   | OR | OFF | 2009/03/31<br>12:08 |
| S14 | 1312 | (silicon adj nitride) with tensile with stress   | US-PGPUB;<br>USPAT  | OR | OFF | 2009/03/31<br>14:25 |
| S15 | 381  | S14 and gate and source and drain and spacer   | US-PGPUB;<br>USPAT  | OR | OFF | 2009/03/31<br>14:25 |
| S16 | 2    | "20070093030"  | US-PGPUB;<br>USPAT;<br>USOCR; FPRS;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | OFF | 2009/03/31<br>16:03 |
| S17 | 2    | wo-2005064665-\$.did.  | US-PGPUB;<br>USPAT;<br>USOCR; FPRS;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | OFF | 2009/03/31<br>16:05 |
| S18 | 2    | ep-1692717-\$.did.   | US-PGPUB;<br>USPAT;<br>USOCR; FPRS;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | OFF | 2009/03/31<br>16:07 |

3/31/2009 5:42:07 PM

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